











SN74AUP1G02

SCES568I -JUNE 2004-REVISED SEPTEMBER 2016

SN74AUP1G02 Low-Power Single 2-Input Positive-NOR Gate

Features

- Available in the Ultra Small 0.64 mm² Package (DPW) with 0.5-mm Pitch
- Low Static-Power Consumption $(I_{CC} = 0.9 \, \mu A \, Max)$
- Low Dynamic-Power Consumption $(C_{pd} = 4.3 pF Typ at 3.3 V)$
- Low Input Capacitance (C_i = 1.5 pF Typ)
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- I_{off} Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Input Hysteresis Allows Slow Input Transition and Better Switching-Noise Immunity at the Input $(V_{hys} = 250 \text{ mV Typ at } 3.3 \text{ V})$
- Wide Operating V_{CC} Range of 0.8 V to 3.6 V
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal
- $t_{pd} = 4.6 \text{ ns Max at } 3.3 \text{ V}$
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

Simplified Schematic



2 Applications

- **ATCA Solutions**
- Active Noise Cancellation (ANC)
- Barcode Scanner
- **Blood Pressure Monitor**
- **CPAP Machine**
- Cable Solutions
- DLP 3D Machine Vision, Hyperspectral Imaging, Optical Networking, and Spectroscopy
- E-Book
- Embedded PC
- Field Transmitter: Temperature or Pressure Sensor
- Fingerprint Biometrics
- HVAC: Heating, Ventilating, and Air Conditioning
- Network-Attached Storage (NAS)
- Server Motherboard and PSU
- Software Defined Radio (SDR)
- TV: High-Definition (HDTV), LCD, and Digital
- Video Communications System
- Wireless Data Access Card, Headset, Keyboard, Mouse, and LAN Card
- X-ray: Baggage Scanner, Medical, and Dental

3 Description

This single 2-input positive-NOR gate performs the Boolean function $Y = \overline{A} + \overline{B}$ or $Y = \overline{A} \times \overline{B}$ in positive logic.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	SOT-23 (5)	2.90 mm × 1.60 mm		
	SC70 (5)	2.00 mm × 1.25 mm		
	SOT (5)	1.60 mm × 1.20 mm		
SN74AUP1G02	SON (6)	1.45 mm × 1.00 mm		
	SON (6)	1.00 mm × 1.00 mm		
	X2SON (5)	0.80 mm × 0.80 mm		
	DSBGA (6)	1.76 mm × 0.76 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.



Table of Contents

1 2 3	Features 1 Applications 1 Description 1	8	Detailed Description 8.1 Overview 8.2 Functional Block Diagram	11 11
4 5 6	Pin Configuration and Functions 3 Specifications 4	9	8.3 Feature Description	11
	6.1 Absolute Maximum Ratings 4 6.2 ESD Ratings 4 6.3 Recommended Operating Conditions 5	10	9.1 Application Information	12
	6.4 Thermal Information	11	11.1 Layout Guidelines	14
	6.7 Switching Characteristics, $C_L = 10 \text{ pF}$	12	Device and Documentation Support 12.1 Receiving Notification of Documentation Updates 12.2 Community Resources	15 15 15
7	Parameter Measurement Information 9 7.1 Propagation Delays, Setup and Hold Times, and Pulse Duration 9 7.2 Enable and Disable Times 10	13	12.5 Glossary Mechanical, Packaging, and Orderable Information	15

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

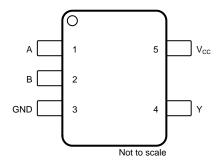
CI	hanges from Revision H (June 2014) to Revision I	Page
•	Added missing packages and body size to Device Information table	1
•	Updated pinout images to new format	3
•	Updated Pin Functions table	3
•	Moved Storage temperature, T _{stg} to <i>Absolute Maximum Ratings</i>	4
	Changed Handling Ratings table to ESD Ratings table	
•	Added Receiving Notification of Documentation Updates section and Community Resources section	15

CI	hanges from Revision G (March 2010) to Revision H	Page
•	Updated document to new TI data sheet format	1
•	Deleted Ordering Information table.	1
•	Updated I _{off} in Features	1
•	Added Applications	1
•	Added DPW Package.	3
•	Added Handling Ratings table	4
•	Added Thermal Information table.	5
•	Added Typical Characteristics.	8

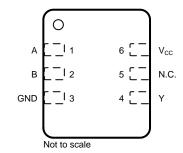


5 Pin Configuration and Functions

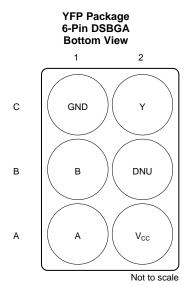
DBV, DCK, or DRL Package 5-Pin SOT-23, SC70, or SOT Top View



DRY or DSF Package 6-Pin SON Top View

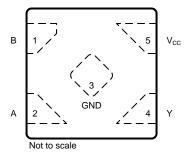


N.C. - No internal connection



DNU - Do not use

DPW Package 5-Pin X2SON Top View



See mechanical drawings for dimensions.

Pin Functions

		PIN				
NAME	DBV, DCK, DRL	DPW	DRY, DSF	YFP	I/O	DESCRIPTION
Α	1	2	1	A1	I	Input A
В	2	1	2	B1	I	Input B
DNU	_	_	_	B2	_	Do not use
GND	3	3	3	C1	_	Ground
N.C.	_	_	5	_	_	No internal connection
Υ	4	4	4	C2	0	Output Y
VCC	5	5	6	A2	_	Power Pin



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		-0.5	4.6	V
V_{I}	Input voltage ⁽²⁾			4.6	V
Vo	Voltage range applied to any output in the high-impedance or power-off state (2)		-0.5	4.6	V
Vo	Output voltage range in the high or low state (2)		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		- 50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V _{CC} or GND			±50	mA
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
\/	Electrostatic	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	2000	
V _(ESD)	discharge	Charged device model (CDM), per JEDEC specification JESD22-C101 (2)	1000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

Submit Documentation Feedback

Copyright © 2004–2016, Texas Instruments Incorporated

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.



6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage		0.8	3.6	V
		V _{CC} = 0.8 V	V _{CC}		
.,	High level input vallens	V _{CC} = 1.1 V to 1.95 V	0.65 × V _{CC}		V
V_{IH}	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6		V
		V _{CC} = 3 V to 3.6 V	2		
		V _{CC} = 0.8 V		0	
.,	Low lovel input valtage	V _{CC} = 1.1 V to 1.95 V		0.35 × V _{CC}	V
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V
		V _{CC} = 3 V to 3.6 V		0.9	
V _I	Input voltage		0	3.6	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 0.8 V		-20	μА
		V _{CC} = 1.1 V		-1.1	
	Libert Level autout aumont	V _{CC} = 1.4 V		-1.7	
l _{OH}	High-level output current	V _{CC} = 1.65 V		-1.9	mA
		V _{CC} = 2.3 V		-3.1	
	High-level output current	V _{CC} = 3 V		-4	
		V _{CC} = 0.8 V		20	μА
		V _{CC} = 1.1 V		1.1	
ı	Lour lovel output ourrent	V _{CC} = 1.4 V		1.7	
OL	Low-level output current	V _{CC} = 1.65 V		1.9	mA
		V _{CC} = 2.3 V		3.1	
		V _{CC} = 3 V		4	
Δt/Δν	Input transition rise or fall rate	V _{CC} = 0.8 V to 3.6 V		200	ns/V
T _A	Operating free-air temperature		-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

6.4 Thermal Information

				SN74AI	JP1G02			
	THERMAL METRIC ⁽¹⁾		DCK (SC70)	DPW (X2SON)	DRL (SOT)	DRY (SON)	DSF (SON)	UNIT
		5 PINS	5 PINS	5 PINS	5 PINS	6 PINS	6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	298.6	314.4	291.8	349.7	554.9	407.1	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	240.2	128.7	224.2	120.5	385.4	232	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	134.6	100.6	245.8	171.4	388.2	306.9	°C/W
ΨЈТ	Junction-to-top characterization parameter	114.5	7.1	31.4	10.8	159	40.3	°C/W
ΨЈВ	Junction-to-board characterization parameter	133.9	99.8	245.6	169.4	384.1	306	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	195.4	n/a	n/a	n/a	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETER	TEST CONDITIONS	V	1	_A = 25°C	$T_A = -40$ °C t	o +85°C	LINUT	
PARAMETER	TEST CONDITIONS	NS Vcc MIN TYP MAX	MIN	MAX	UNIT			
	I _{OH} = -20 μA	0.8 V to 3.6 V	V _{CC} - 0.1		V _{CC} - 0.1			
	I _{OH} = -1.1 mA	1.1 V			0.7 × V _{CC}			
	$I_{OH} = -1.7 \text{ mA}$	1.4 V	1.11		1.03			
PARAMETER VOH VOL II A or B inputs Ioff ΔIoff Icc ΔIcc Ci Co	$I_{OH} = -1.9 \text{ mA}$	1.65 V	1.32		1.3		V	
	$I_{OH} = -2.3 \text{ mA}$	221/	2.05		1.97			
	$I_{OH} = -3.1 \text{ mA}$	2.3 V	1.9		1.85			
	$I_{OH} = -2.7 \text{ mA}$	0.1/	2.72		2.67			
	$I_{OH} = -4 \text{ mA}$	3 V	2.6		2.55			
	I _{OL} = 20 μA	0.8 V to 3.6 V		0.1		0.1		
	I _{OL} = 1.1 mA	1.1 V		0.3 × V _{CC}		$0.3 \times V_{CC}$		
	I _{OL} = 1.7 mA	1.4 V		0.31		0.37		
	I _{OL} = 1.9 mA	1.65 V		0.31		0.35		
V_{OL}	I _{OL} = 2.3 mA	0.01/		0.31		0.33	V	
	I _{OL} = 3.1 mA	2.3 V		0.44		0.45		
	I _{OL} = 2.7 mA	2.1/		0.31		0.33		
	I _{OL} = 4 mA	3 V		0.44		0.45		
	V _I = GND to 3.6 V	0 V to 3.6 V		0.1		0.5	μА	
I _{off}	V_I or $V_O = 0 V$ to 3.6 V	0 V		0.2		0.6	μΑ	
$\Delta I_{ m off}$	V_I or $V_O = 0 V$ to 3.6 V	0 V to 0.2 V		0.2		0.6	μΑ	
I _{CC}	$V_I = GND \text{ or } (V_{CC} \text{ to } 3.6 \text{ V}),$ $I_O = 0$	0.8 V to 3.6 V		0.5		0.9	μА	
Δl _{CC}	$V_I = V_{CC} - 0.6 V^{(1)},$ $I_O = 0$	3.3 V		40		50	μΑ	
<u></u>	V V or CND	0 V		1.5			~F	
C _i	$V_I = V_{CC}$ or GND	3.6 V		1.5			pF	
C _o	V _O = GND	0 V		3			pF	

⁽¹⁾ One input at V_{CC} – 0.6 V, other input at V_{CC} or GND.

6.6 Switching Characteristics, $C_L = 5 pF$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3 and Figure 4)

DADAMETED	FROM	то	V	T,	4 = 25°C	;	$T_A = -40^{\circ}C$ to	+85°C	UNIT			
PARAMETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNII			
		Y	0.8 V		19.3							
						1.2 V ± 0.1 V	2.6	7.3	13	2.1	16.3	
4	A or B		1.5 V ± 0.1 V	1.4	5.2	8.9	0.9	10.8	no			
t _{pd}	AUID		1	'	1.8 V ± 0.15 V	1	4.2	6.8	0.5	8.7	ns	
					2.5 V ± 0.2 V	1	3	4.6	0.5	5.9		
			3.3 V ± 0.3 V	1	2.4	3.7	0.5	4.6				



6.7 Switching Characteristics, $C_L = 10 pF$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T _A	= 25°C		$T_A = -40^{\circ}C$ to	+85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V _{CC}	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		22.3				
		A or B Y	1.2 V ± 0.1 V	1.5	8.5	14.9	1	17.9	
	A or B		1.5 V ± 0.1 V	1	6.2	10.2	0.5	11.8	20
t _{pd}			1.8 V ± 0.15 V	1	5	7.9	0.5	9.5	ns
			2.5 V ± 0.2 V	1	3.6	5.4	0.5	6.5	
			3.3 V ± 0.3 V	1	2.9	4.4	0.5	5	

6.8 Switching Characteristics, $C_L = 15 pF$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3 and Figure 4)

DADAMETED	FROM	то	V	T	= 25°C	;	$T_A = -40^{\circ}C$ to	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	V _{CC}	MIN	TYP	MAX	MIN	MAX	ONIT
			0.8 V		25				
	A or B		1.2 V ± 0.1 V	3.6	9.9	16.5	3.1	20.6	
		Y	1.5 V ± 0.1 V	2.3	7.2	11.3	1.8	13.7	
t _{pd}			1.8 V ± 0.15 V	1.6	5.8	8.9	1.1	11.1	ns
			2.5 V ± 0.2 V	1	4.3	6.1	0.5	7.7	-
			3.3 V ± 0.3 V	1	3.4	5	0.5	6.2	

6.9 Switching Characteristics, $C_L = 30 pF$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3 and Figure 4)

DADAMETED	FROM	то	V	T,	_λ = 25°C		$T_A = -40^{\circ}C$ to	+85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V _{CC}	MIN	TYP	MAX	MIN	MAX	
			0.8 V		34.6				
	A or B	Y	1.2 V ± 0.1 V	4.9	13.1	21.1	4.4	26.2	
			1.5 V ± 0.1 V	3.4	9.5	14.4	2.9	17.4	
t _{pd}			1.8 V ± 0.15 V	2.5	7.7	11.2	2	14	ns
			2.5 V ± 0.2 V	1.8	5.7	7.8	1.3	9.8	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	1.5	4.7	6.4	1	7.8	

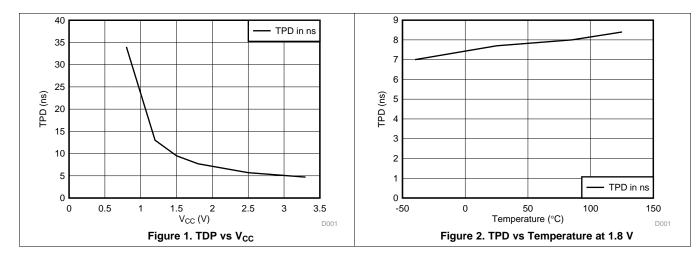
6.10 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			0.8 V	4.1	
		1.2 V ± 0.1 V	4.1		
<u> </u>	Power dissipation capacitance	f = 10 MHz	1.5 V ± 0.1 V	4.1	pF
C _{pd}	Fower dissipation capacitance	I = IO WINZ	1.8 V ± 0.15 V	4.1	
			2.5 V ± 0.2 V	4.2	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	4.3	



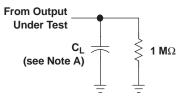
6.11 Typical Characteristics





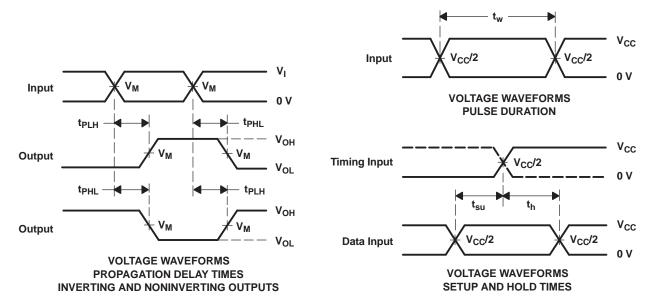
7 Parameter Measurement Information

7.1 Propagation Delays, Setup and Hold Times, and Pulse Duration



LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V _{CC} = 2.5 V ± 0.2 V	V _{CC} = 3.3 V ± 0.3 V
C _L V _M	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}



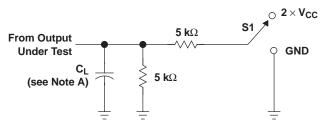
NOTES: A. C_L includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f/t_f = 3 \text{ ns}$.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd} .
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



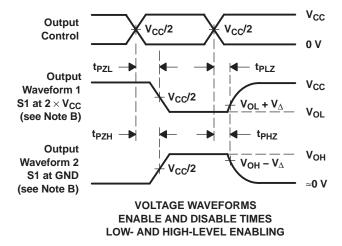
7.2 Enable and Disable Times



TEST	S1
t_{PLZ}/t_{PZL}	$2 \times V_{CC}$
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
C _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
V _I	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V _∆	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 $\Omega,\,t_r/t_f$ = 3 ns .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

Product Folder Links: SN74AUP1G02

ubinit Documentation Feedback



8 Detailed Description

8.1 Overview

The SN74LVC1G02 device contains one 2-input positive-NOR gate and performs the Boolean function $Y = \overline{A} + \overline{B}$ or $Y = \overline{A} \times \overline{B}$.

The AUP family of devices has quiescent power consumption less than 1 μ A and comes in the ultra small DPW package. The DPW package technology is a major breakthrough in IC packaging. Its tiny 0.64 mm square footprint saves significant board space over other package options while still retaining the traditional manufacturing friendly lead pitch of 0.5 mm.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered. The I_{off} feature also allows for live insertion.

8.2 Functional Block Diagram



8.3 Feature Description

- Wide operating V_{CC} range of 0.8 V to 3.6 V
- 3.6-V I/O tolerant to support down translation
- · Input hysteresis allows slow input transition and better switching noise immunity at the input
- I_{off} feature allows voltages on the inputs and outputs when V_{CC} is 0 V
- · Low noise due to slower edge rates

8.4 Device Functional Modes

Table 1 shows the functional modes of SN74AUP1G02.

Table 1. Function Table

INP	UTS	OUTPUT
Α	В	Υ
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static and dynamic power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in an increased battery life. This product also maintains excellent signal integrity. It has a small amount of hysteresis built in allowing for slower or noisy input signals. The lowered drive produces slower edges and prevents overshoot and undershoot on the outputs.

9.2 Typical Application

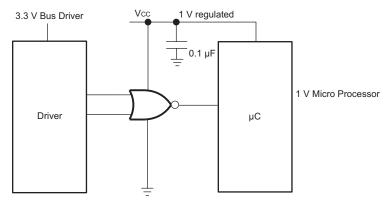


Figure 5. Typical Application Schematic

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits.

9.2.2 Detailed Design Procedure

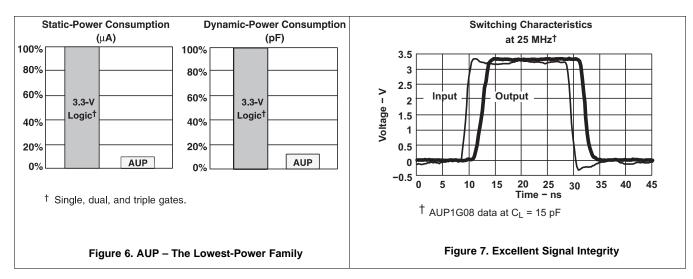
- 1. Recommended Input conditions
 - Rise time and fall time specs. See (Δt/ΔV) in Recommended Operating Conditions
 - Specified high and low levels. See (V_{IH} and V_{II}) in Recommended Operating Conditions
 - Inputs are overvoltage tolerant allowing them to go as high as 3.6 V at any valid V_{CC}
- 2. Recommend output conditions
 - Load currents should not exceed 20 mA on the output and 50 mA total for the part
 - Outputs should not be pulled above V_{CC}

Submit Documentation Feedback



Typical Application (continued)

9.2.3 Application Curves



The AUP family of single gate logic makes excellent translators for the new lower voltage microprocessors that typically are powered from 0.8 V to 1.2 V. They can drop the voltage of peripheral drivers and accessories that are still powered by 3.3 V to the new uC power levels.



10 Power Supply Recommendations

The power supply can be any voltage between the Min and Max supply voltage rating located in the Recommended Operating Conditions table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μF is recommended; if there are multiple V_{CC} pins, then 0.01 μF or 0.022 μF is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μF and a 1 μF are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

11 Layout

11.1 Layout Guidelines

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Figure 8 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the output section of the part when asserted. This will not disable the input section of the I/Os, so they cannot float when disabled.

11.2 Layout Example

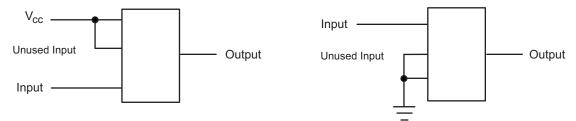


Figure 8. Layout Diagram

Submit Documentation Feedback



12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74AUP1G02DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H02R	Samples
SN74AUP1G02DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H02R	Samples
SN74AUP1G02DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HB5, HBF, HBK, HB R)	Samples
SN74AUP1G02DCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HB5, HBR)	Samples
SN74AUP1G02DPWR	ACTIVE	X2SON	DPW	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	B4	Samples
SN74AUP1G02DRLR	ACTIVE	SOT-5X3	DRL	5	4000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	(HB7, HBR)	Samples
SN74AUP1G02DRY2	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	НВ	Samples
SN74AUP1G02DRYR	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	НВ	Samples
SN74AUP1G02DSFR	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	НВ	Samples
SN74AUP1G02YFPR	ACTIVE	DSBGA	YFP	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM		HBN	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



PACKAGE OPTION ADDENDUM

10-Dec-2020

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

24-Jul-2020 www.ti.com

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1G02DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G02DBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G02DCKR	SC70	DCK	5	3000	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74AUP1G02DCKR	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AUP1G02DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AUP1G02DCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74AUP1G02DPWR	X2SON	DPW	5	3000	178.0	8.4	0.91	0.91	0.5	2.0	8.0	Q3
SN74AUP1G02DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74AUP1G02DRLR	SOT-5X3	DRL	5	4000	180.0	9.5	1.78	1.78	0.69	4.0	8.0	Q3
SN74AUP1G02DRY2	SON	DRY	6	5000	180.0	9.5	1.6	1.15	0.75	4.0	8.0	Q3
SN74AUP1G02DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74AUP1G02DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74AUP1G02YFPR	DSBGA	YFP	6	3000	178.0	9.2	0.89	1.29	0.62	4.0	8.0	Q1

www.ti.com 24-Jul-2020



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1G02DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74AUP1G02DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74AUP1G02DCKR	SC70	DCK	5	3000	202.0	201.0	28.0
SN74AUP1G02DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74AUP1G02DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74AUP1G02DCKT	SC70	DCK	5	250	202.0	201.0	28.0
SN74AUP1G02DPWR	X2SON	DPW	5	3000	205.0	200.0	33.0
SN74AUP1G02DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0
SN74AUP1G02DRLR	SOT-5X3	DRL	5	4000	184.0	184.0	19.0
SN74AUP1G02DRY2	SON	DRY	6	5000	184.0	184.0	19.0
SN74AUP1G02DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74AUP1G02DSFR	SON	DSF	6	5000	184.0	184.0	19.0
SN74AUP1G02YFPR	DSBGA	YFP	6	3000	220.0	220.0	35.0



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4211218-3/D







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. The size and shape of this feature may vary.





NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).





NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





DIE SIZE BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.





PLASTIC SMALL OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-293 Variation UAAD-1



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE



NOTES: (continued)



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

^{8.} Board assembly site may have different recommendations for stencil design.

DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.









NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.





NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).





NOTES: (continued)

Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC registration MO-287, variation X2AAF.





NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).





4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

^{8.} Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022, Texas Instruments Incorporated